查询"2N1495"供应商

PNP Power Transistors

CASE TO-5/TO-39
$I_{C(MAX)}$ = 0.05-5A
$V_{CEO(SUS)}$ = 40-450V

Type No.	NPN complement	V_{CEO} (sus) (V)	I_C (max) (A)	h_{FE}@Ic/Vce (min-max @ A/V)	$V_{CE(SAT)}$ @ Ic/IB (V @ A/A)	V_{BE} @ Ic/VCE (V @ A/V)	I_{CEV} @VCE (mA @ V)	PD@ T_C = 100°C (Watts)	Cob (pf)	fr (MHz)	ton @ Ic/IB (µs @ A/A)	tOFF @ IC/IB (µs @ A/A)
2N3743	2N3742	300	.05	25-250 @ .03/10	8 @ .03/.003	1.2[c] @ .03/.003	.0003[b] @ 200	5		10[t]		
2N3867		40	3	>25 @ 2.5/3	1.3 @ 2.5/.25	2.2 @ 2.5/.25	.001 @ 40	6	120	60	.3[t] @ 1/.1	1.2[t] @ 1/.1
2N3868		60	3	>25 @ 2.5/3	1.3 @ 2.5/.25	2.2 @ 2.5/.25	.001 @ 60	6	120	60	.3[t] @ 1/.1	1.2[t] @ 1/.1
2N4930	2N4926	200	.05	20-200 @ .01/10	5 @ .01/.001	1 @ .01/10	.1[b] @ 200	5	20	10[t]		
2N4931	2N4927	250	.05	20-200 @ .01/10	5 @ .01/.001	1 @ .01/10	.1[b] @ 250	5	20	10[t]		
2N5091		300	1	20-200 @ .1/15	3 @ .025/.0025	1 @ .025/10	.1[b] @ 350	4	20	10[t]		
2N5093	2N5092	350	1	20-200 @ .1/15	3 @ .025/.0025	1 @ .025/10	.1[b] @ 400	4	20	10[t]		
2N5094	2N5095	400	1	20-200 @ .1/15	3 @ .025/.0025	1 @ .025/10	.1[b] @ 450	4	20	10[t]		
2N5096	2N5097	450	1	20-200 @ .1/15	3 @ .025/.0025	1 @ .025/10	.1[b] @ 500	4	20	10[t]		
2N5147	2N5148	80	2	30-90 @ 1/5	.85 @ 2/.2	1.5 @ 2/5	1 @ 100	6	120	50	.3[t] @ 1/.1	1.2[t] @ 1/.1
2N5149	2N5150	80	5	70-200 @ 1/5	.85 @ 2/.2	1.5 @ 2/5	1 @ 100	6	120	60	.3[t] @ 1/.1	1.2[t] @ 1/.1
2N5151	2N5152	80	5	30-90 @ 2.5/5	.75 @ 2.5/.25	1.45 @ 2.5/5	1 @ 100	10	250	60	.3[t] @ 1/.1	1.2[t] @ 1/.1
2N5153	2N5154	80	5	70-200 @ 2.5/5	.75 @ 2.5/.25	1.45 @ 2.5/5	1 @ 100	10	250	60	.3[t] @ 1/.1	1.2[t] @ 1/.1
2N5415	2N3440	200	1	30-150 @ .05/10	2.5 @ .05/.005	1.5 @ .05/10	.05 @ 200	10	15	15		
2N5416	2N3439	300	1	30-150 @ .05/10	2 @ .05/.005	1.5 @ .05/10	.05 @ 300	10	15	15		

NOTES: b) ICBO @ VCB (mA @ V) c) VBE (SAT) @ IC/IB (V @ A/A) t) (typical)

NPN Power Transistors

CASE TO-8
$I_{(MAX)}$ = 1-3A
$V_{CEO(SUS)}$ = 40-55V

Type No.		VCEO (sus) (V)	IC (max) (A)	h_{FE}@Ic/Vce (min-max @ A/V)	VCE(SAT) @ IC/IB (V @ A/A)	VBE @ IC/VCE (V @ A/V)	ICEV @VCE (mA @ V)	PD@ TC = 25°C (Watts)	Is/b@VCE t = 1 sec (A @ V)	fr (MHz)	ton @ Ic/IB (µs @ A/A)	tOFF @ IC/IB (µs @ A/A)
2N1483		40	3	20-60 @ .75/4	2 @ .75/.075	3.5 @ .75/4	.015[b] @ 30	25	1[t] @ 25	1.25	.3[t] @ 1/.1	6[t] @ 1/.1
2N1484		55	3	20-60 @ .75/4	2 @ .75/.075	3.5 @ .75/4	.015[b] @ 30	25	1[t] @ 25	1.25	.3[t] @ 1/.1	6[t] @ 1/.1
2N1495		40	3	35-100 @ .75/4	.75 @ .75/4	2.5 @ .75/4	.015[b] @ 30	25	1[t] @ 25	1.25	.3[t] @ 1/.1	6[t] @ 1/.1
2N1486		55	3	35-100 @ .75/4	2.5 @ .75/4	2.5 @ .75/4	.015[b] @ 30	25	1[t] @ 25	1.25	.3[t] @ 1/.1	6[t] @ 1/.1
2N1701		40	2.5	20-80 @ 3/4	3 @ .3/4	3 @ .3/4	.75[b] @ 60	25	1[t] @ 25	0.35	.3[t] @ 1/.1	6[t] @ 1/.1

NOTES: b) ICBO @ VCB (mA @ V) t) (typical)

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